



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts,Customers Priority,Honest Operation,and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Parameter	Tr1 and Tr2
V_{CEO}	50V
I_C	150mA

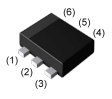
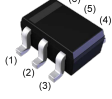
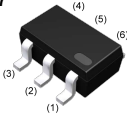
●Features

- 1) Two 2SC2412K chips in a EMT, UMT or SMT package.
- 2) Mounting possible with EMT3, UMT3 or SMT3 automatic mounting machines.
- 3) Transistor elements are independent, eliminating interference.
- 4) Mounting cost and area can be cut in half.

●Application

GENERAL PURPOSE SMALL SIGNAL AMPLIFIER

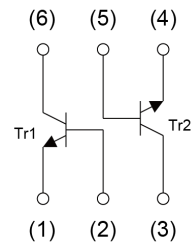
●Outline

<p>SOT-563</p>  <p>EMX1 (EMT6)</p>	<p>SOT-363</p>  <p>UMX1N (UMT6)</p>
<p>SOT-457</p>  <p>IMX1 (SMT6)</p>	

●Inner circuit

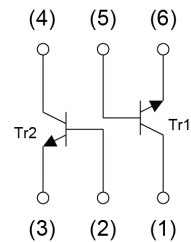
EMX1 / UMX1N

- (1) Tr1 Emitter
- (2) Tr1 Base
- (3) Tr2 Collector
- (4) Tr2 Emitter
- (5) Tr2 Base
- (6) Tr1 Collector



IMX1

- (1) Tr1 Collector
- (2) Tr2 Base
- (3) Tr2 Emitter
- (4) Tr2 Collector
- (5) Tr1 Base
- (6) Tr1 Emitter



●Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
EMX1	SOT-563 (EMT6)	1616	T2R	180	8	8000	X1
UMX1N	SOT-363 (UMT6)	2021	TN	180	8	3000	X1
IMX1	SOT-457 (SMT6)	2928	T110	180	8	3000	X1

● **Absolute maximum ratings** ($T_a = 25^\circ\text{C}$)

<For Tr1 and Tr2 in common>

Parameter		Symbol	Values	Unit
Collector-base voltage		V_{CBO}	60	V
Collector-emitter voltage		V_{CEO}	50	V
Emitter-base voltage		V_{EBO}	7	V
Collector current		I_C	150	mA
Power dissipation	EMX1/ UMX1N	$P_D^{*1 *2}$	150	mW/Total
	IMX1	$P_D^{*1 *3}$	300	mW/Total
Junction temperature		T_j	150	$^\circ\text{C}$
Range of storage temperature		T_{stg}	-55 to +150	$^\circ\text{C}$

● **Electrical characteristics** ($T_a = 25^\circ\text{C}$)

<For Tr1 and Tr2 in common>

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Collector-base breakdown voltage	BV_{CBO}	$I_C = 50\mu\text{A}$	60	-	-	V
Collector-emitter breakdown voltage	BV_{CEO}	$I_C = 1\text{mA}$	50	-	-	V
Emitter-base breakdown voltage	BV_{EBO}	$I_E = 50\mu\text{A}$	7	-	-	V
Collector cut-off current	I_{CBO}	$V_{CB} = 60\text{V}$	-	-	100	nA
Emitter cut-off current	I_{EBO}	$V_{EB} = 7\text{V}$	-	-	100	nA
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 50\text{mA}, I_B = 5\text{mA}$	-	-	400	mV
DC current gain	h_{FE}	$V_{CE} = 6\text{V}, I_C = 1\text{mA}$	120	-	560	-
Transition frequency	f_T	$V_{CE} = 12\text{V}, I_E = -2\text{mA}, f = 100\text{MHz}$	-	180	-	MHz
Output capacitance	C_{ob}	$V_{CB} = 12\text{V}, I_E = 0\text{A}, f = 1\text{MHz}$	-	2.0	3.5	pF

*1 Each terminal mounted on a reference land.

*2 120mW per element must not be exceeded.

*3 200mW per element must not be exceeded.

● Electrical characteristic curves ($T_a = 25^\circ\text{C}$)

<For Tr1 and Tr2 in common>

Fig.1 Ground Emitter Propagation Characteristics

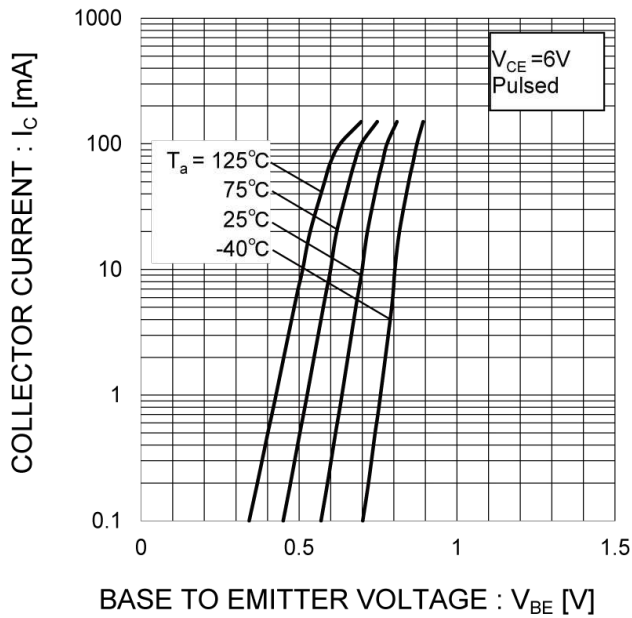


Fig.2 Grounded Emitter Output Characteristics

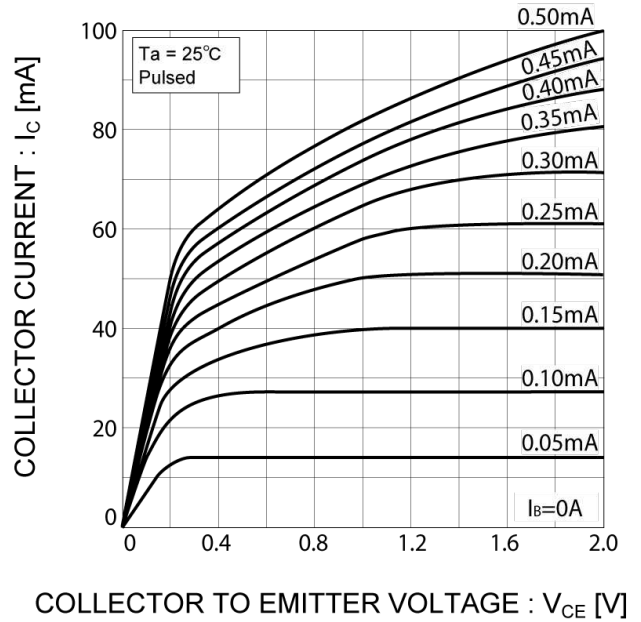


Fig.3 DC Current Gain vs. Collector Current (I)

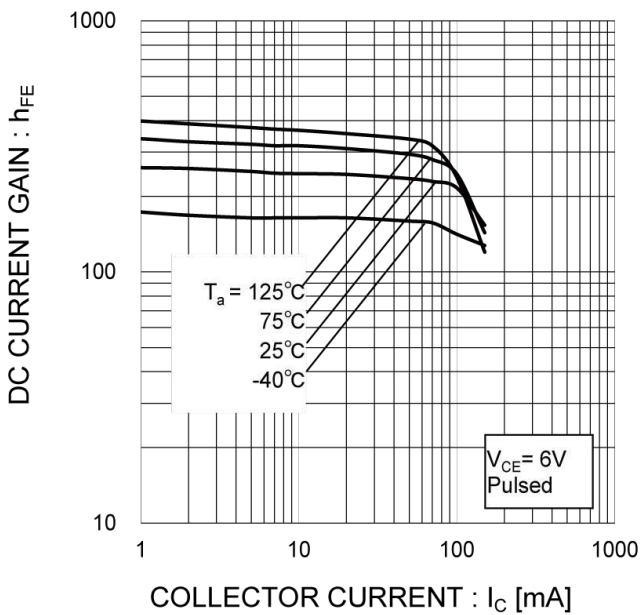
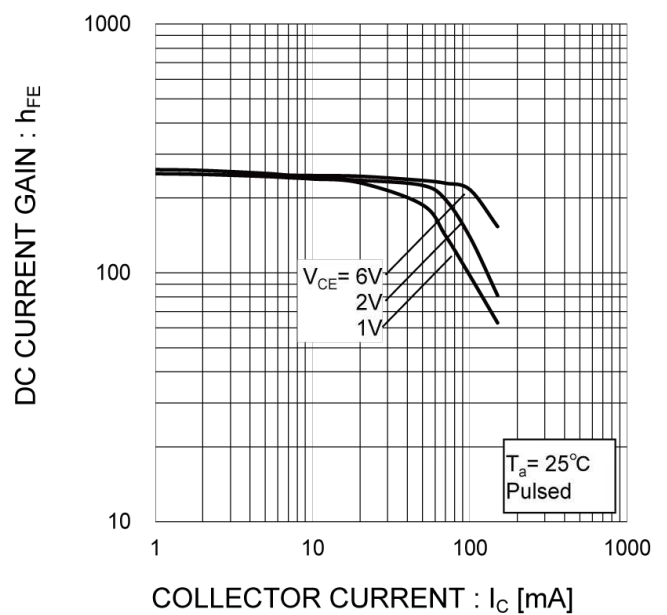


Fig.4 DC Current Gain vs. Collector Current (II)



● **Electrical characteristic curves** ($T_a = 25^\circ\text{C}$)

<For Tr1 and Tr2 in common>

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current(I)

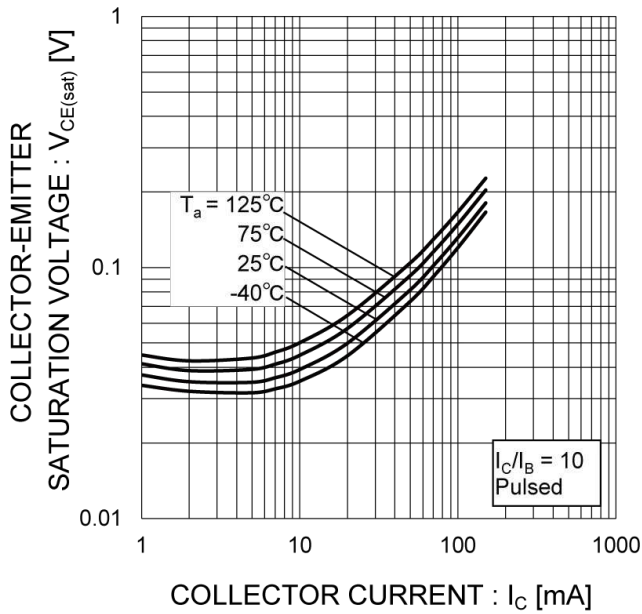


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current(II)

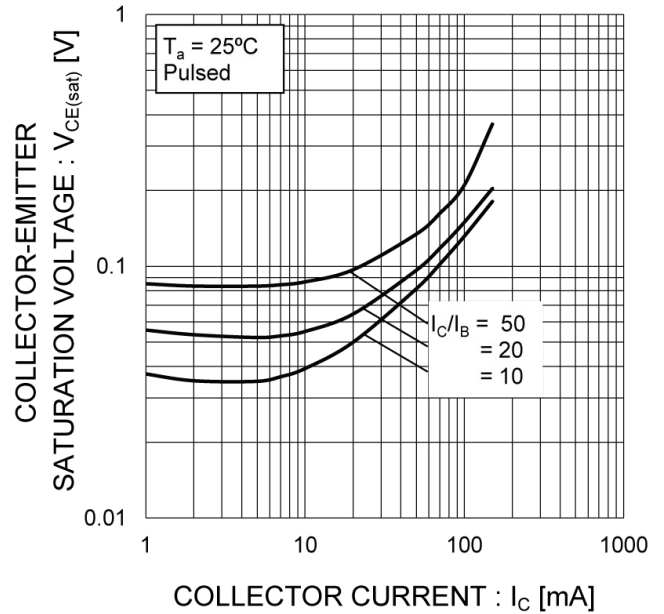


Fig.7 Base-Emitter Saturation Voltage vs. Collector Current (I)

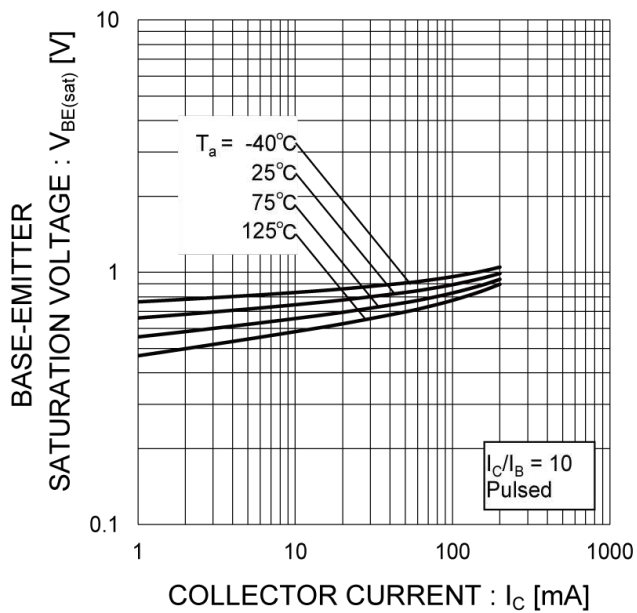
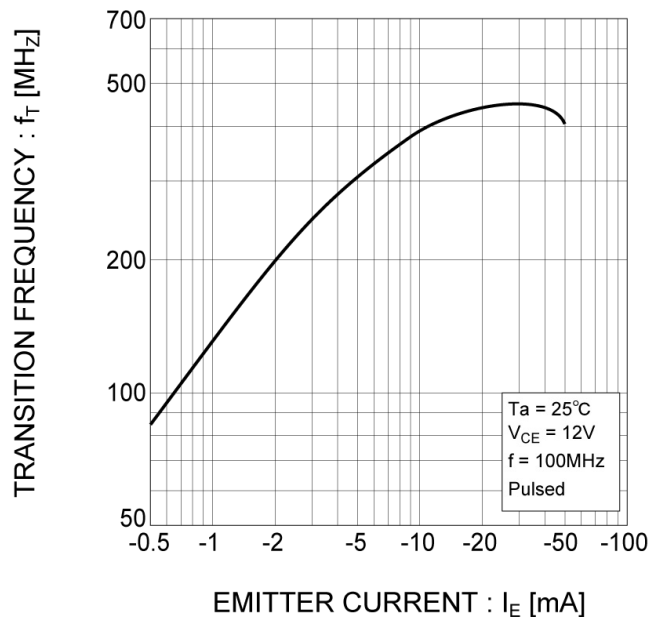


Fig.8 Gain Bandwidth Product vs. Emitter Current



● Electrical characteristic curves ($T_a = 25^\circ\text{C}$)

<For Tr1 and Tr2 in common>

Fig.9 Collector Output Capacitance vs. Collector-Base Voltage
Emitter Input Capacitance vs. Emitter-Base Voltage

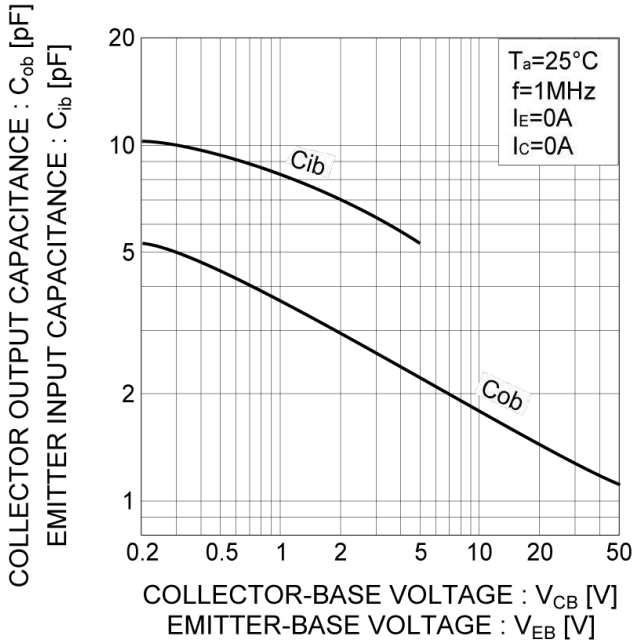


Fig.10 Safe Operating Area

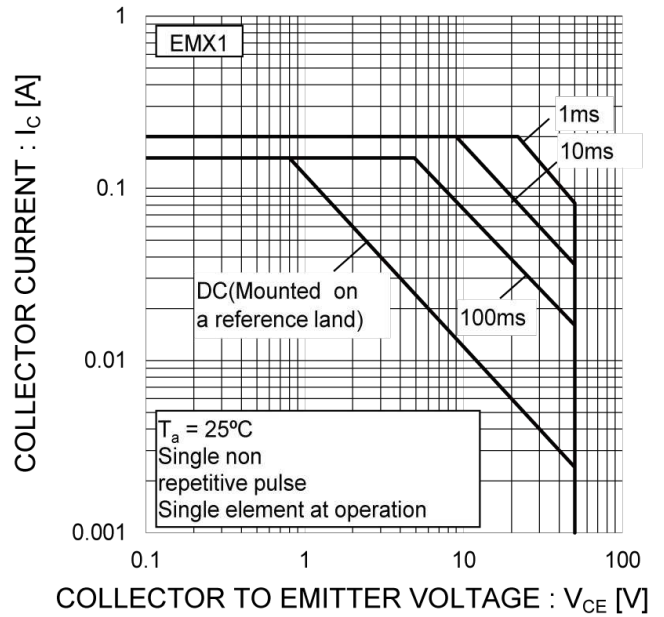


Fig.11 Safe Operating Area

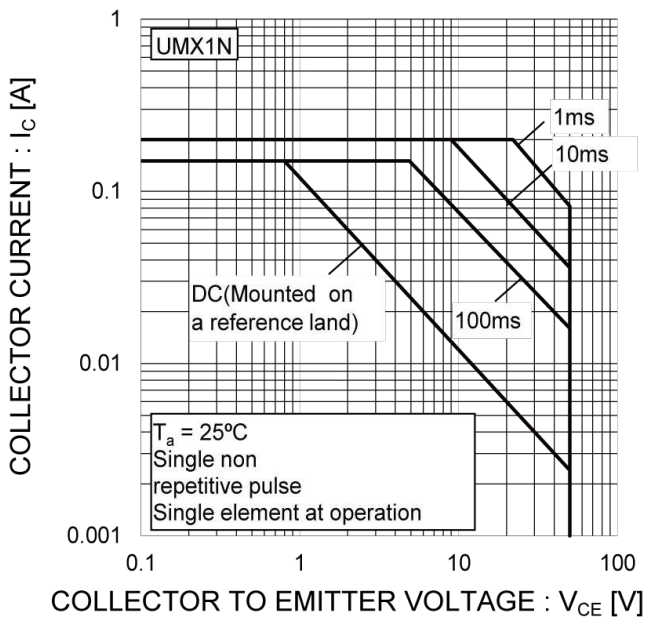
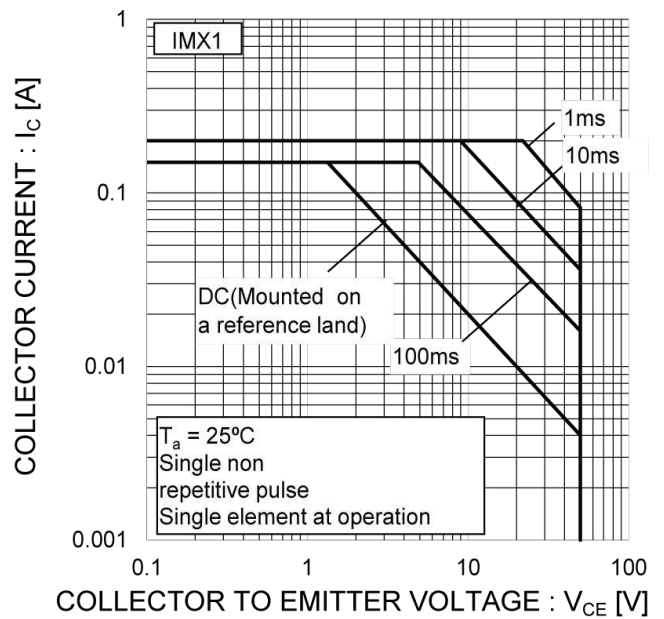
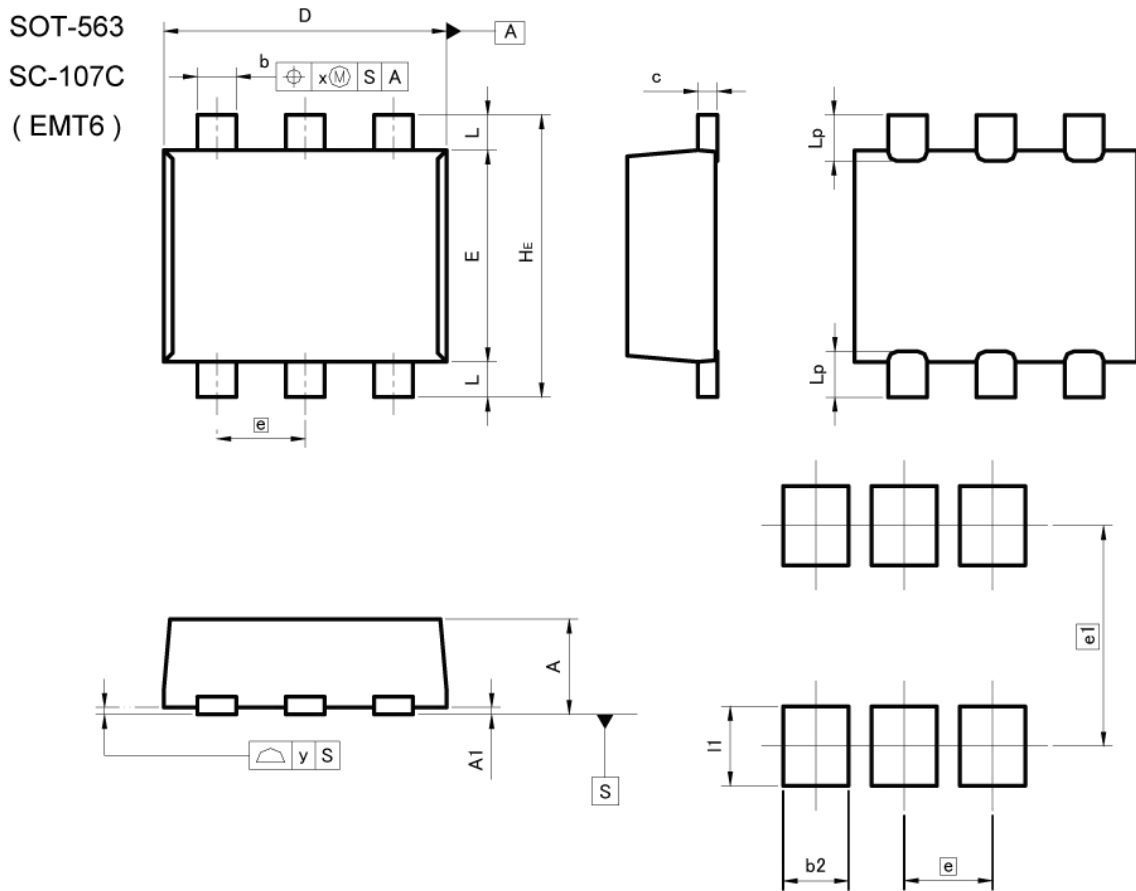


Fig.12 Safe Operating Area



●Dimensions



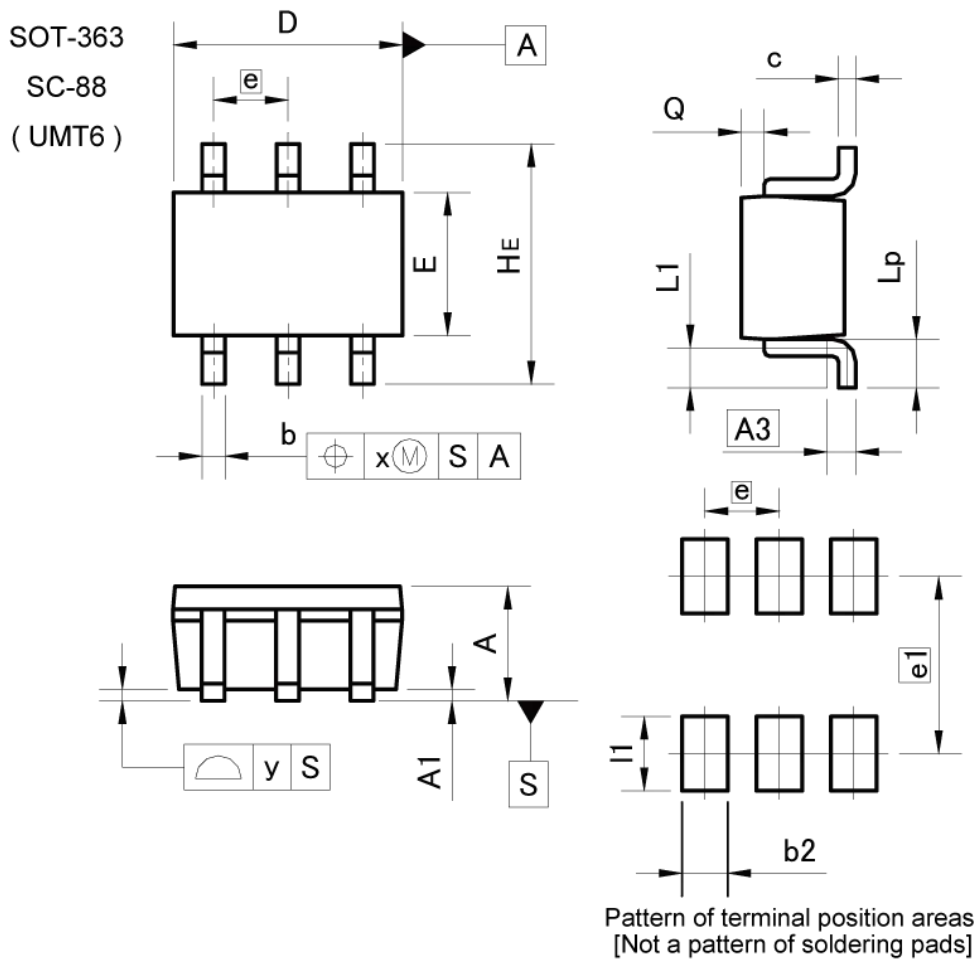
Pattern of terminal position areas
[Not a pattern of soldering pads]

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.45	0.55	0.018	0.022
A1	0.00	0.10	0.000	0.004
b	0.17	0.27	0.007	0.011
c	0.08	0.18	0.003	0.007
D	1.50	1.70	0.059	0.067
E	1.10	1.30	0.043	0.051
e	0.50		0.020	
HE	1.50	1.70	0.059	0.067
L	0.10	0.30	0.004	0.012
Lp	-	0.35	-	0.014
x	-	0.10	-	0.004
y	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	-	0.37	-	0.015
e1	1.25		0.049	
I1	-	0.45	-	0.018

Dimension in mm/inches

●Dimensions



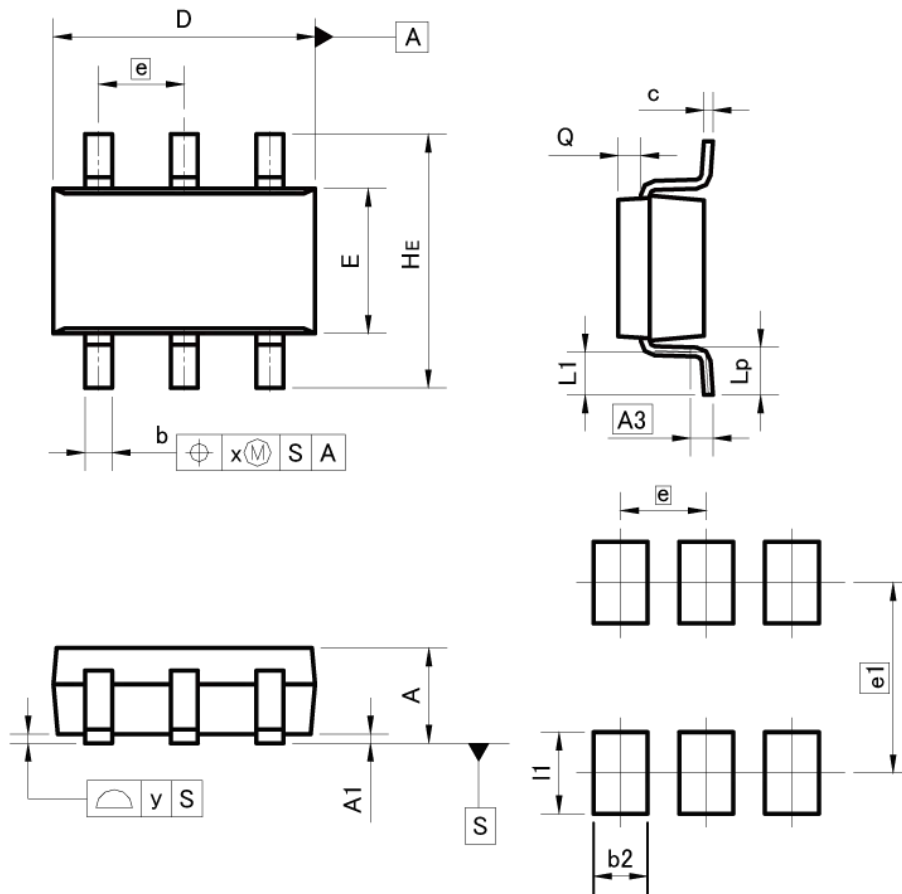
DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.80	1.00	0.031	0.039
A1	0.00	0.10	0.000	0.004
A3	0.25		0.010	
b	0.15	0.30	0.006	0.012
c	0.10	0.20	0.004	0.008
D	1.90	2.10	0.075	0.083
E	1.15	1.35	0.045	0.053
e	0.65		0.026	
HE	2.00	2.20	0.079	0.087
L1	0.20	0.50	0.008	0.020
Lp	0.25	0.55	0.010	0.022
Q	0.10	0.30	0.004	0.012
x	-	0.10	-	0.004
y	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	-	0.40	-	0.016
e1	1.55		0.061	
I1	-	0.65	-	0.026

Dimension in mm/inches

●Dimensions

SOT-457
SC-74
(SMT6)



Pattern of terminal position areas
[Not a pattern of soldering pads]

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.00	1.30	0.039	0.051
A1	0.00	0.10	0.000	0.004
A3	0.25		0.010	
b	0.25	0.40	0.010	0.016
c	0.09	0.25	0.004	0.010
D	2.80	3.00	0.110	0.118
E	1.50	1.80	0.059	0.071
e	0.95		0.037	
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.20	0.30	0.008	0.012
x	-	0.20	-	0.008
y	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	-	0.60	-	0.024
e1	2.10		0.083	
I1	-	0.90	-	0.035

Dimension in mm/inches

Notes

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